

# MC79XX/MC79XXA/LM79XX

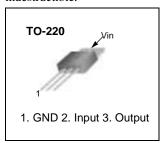
# 3-Terminal 1A Negative Voltage Regulator

### **Features**

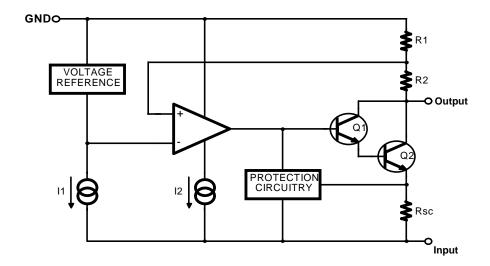
- Output Current in Excess of 1A
- Output Voltages of -5, -6, -8, -9, -10, -12, -15, -18 and -24V
- · Internal Thermal Overload Protection
- · Short Circuit Protection
- Output Transistor Safe Operating Area Compensation

### **Description**

The MC79XX / MC79XXA/ LM79XX series of three terminal negative regulators are available in TO-220 package and with several fixed output voltages, making them useful in a wide range of applications. Each type employs internal current limiting, thermal shut down and safe operating area protection, making it essentially indestructible.



### **Internal Block Digram**



## **Absolute Maximum Ratings**

Parameter	Symbol	Value	Unit
Input Voltage	VI	-35	V
Thermal Resistance Junction-Case (Note1)	R <sub>θ</sub> JC	5	°C/W
Thermal Resistance Junction-Air (Note1, 2)	$R_{ heta JA}$	65	C/ VV
Operating Temperature Range	TOPR	0 ~ +125	°C
Storage Temperature Range	Tstg	-65 ~ +150	°C

#### Note:

- Thermal resistance test board Size: 76.2mm \* 114.3mm \* 1.6mm(1S0P) JEDEC standard: JESD51-3, JESD51-7
- 2. Assume no ambient airflow

### **Electrical Characteristics (MC7905/LM7905)**

(VI = -10V, IO = 500mA,  $0^{\circ}$ C  $\leq$ TJ  $\leq$  +125 $^{\circ}$ C, CI =2.2 $\mu$ F, CO =1 $\mu$ F, unless otherwise specified.)

Parameter	Symbol	Cone	ditions	Min.	Тур.	Max.	Unit
		TJ = +25°C		-4.8	-5.0	-5.2	
Output Voltage	Vo	I <sub>O</sub> = 5mA to 1A, V <sub>I</sub> = -7V to -20V	-	-4.75	-5.0	-5.25	V
Line Regulation (Note3)	ΔVΩ	T <sub>J</sub> = +25°C	V <sub>I</sub> = -7V to -25V	-	35	100	mV
Line Regulation (Notes)	ΔνΟ	1J = +25 C	V <sub>I</sub> = -8V to -12V	-	8	50	IIIV
Load Regulation (Note2)	ΔVΩ	T <sub>J</sub> = +25°C I <sub>O</sub> = 5mA to 1.5	IO = 5mA to 1.5A		10	100	m\/
Load Regulation (Note3)	ΔνΟ	T <sub>J</sub> =+25°C I <sub>O</sub> = 250mA to 7			3	50	mV
Quiescent Current	IQ	T <sub>J</sub> =+25°C	T <sub>J</sub> =+25°C			6	mA
Quiocoont Current Change	AIO.	IO = 5mA to 1A		-	0.05	0.5	mA
Quiescent Current Change	ΔlQ	$V_{I} = -8V \text{ to } -25V$	,	-	0.1	0.8	ША
Temperature Coefficient of VD	ΔVο/ΔΤ	IO = 5mA		-	- 0.4	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100k TA =+25°C	кНz	-	40	-	μV
Ripple Rejection	RR	f = 120Hz ΔVI = 10V		54	60	-	dB
Dropout Voltage	VD	T <sub>J</sub> = +25°C I <sub>O</sub> = 1A		-	2	-	V
Short Circuit Current	Isc	TJ =+25°C, VI =	-35V	-	300	-	mA
Peak Current	IPK	TJ =+25°C		-	2.2	-	Α

<sup>3.</sup> Load and line regulation are specified at constant junction temperature. Changes in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

## Electrical Characteristics (MC7906) (Continued)

(VI = -11V, IO = 500mA,  $0^{\circ}$ C  $\leq$ TJ  $\leq$  +125 $^{\circ}$ C, CI =2.2 $\mu$ F, CO =1 $\mu$ F, unless otherwise specified.)

Parameter	Symbol	Cone	ditions	Min.	Тур.	Max.	Unit
		T <sub>J</sub> = +25°C		-5.75	-6	-6.25	
Output Voltage	Vo	IO = 5mA  to  1A, $V_I = -9V \text{ to } -21V$	Po ≤ 15W	-5.7	-6	-6.3	V
Line Regulation (Note1)	ΔVΩ	T <sub>J</sub> = +25°C	$V_{I} = -8V \text{ to } -25V$	-	10	120	mV
Line Regulation (Note I)	ΔνΟ	1J = +25 C	V <sub>I</sub> = -9V to -13V	-	5	60	IIIV
Load Regulation (Note1)	ΔVο	T <sub>J</sub> = +25°C I <sub>O</sub> = 5mA to 1.5A		-	10	120	mV
Load Negulation (Note 1)	ΔνΟ	TJ =+25°C IO = 250mA to 7			3	60	IIIV
Quiescent Current	IQ	TJ =+25°C		-	3	6	mA
Quiescent Current Change	ΔlQ	IO = 5mA to 1A		-	0.05	0.5	mA
Quiescent Current Change	ΔiQ	V <sub>I</sub> = -8V to -25V		-	0.1	1.3	IIIA
Temperature Coefficient of V <sub>D</sub>	ΔVo/ΔΤ	IO = 5mA		-	-0.5	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100k T <sub>A</sub> =+25°C	Hz	-	130	-	μV
Ripple Rejection	RR	f = 120Hz ΔV <sub>I</sub> = 10V		54	60	-	dB
Dropout Voltage	VD	T <sub>J</sub> = +25°C I <sub>O</sub> = 1A		-	2	-	V
Short Circuit Current	Isc	TJ = +25°C, VI =	-35V	-	300	-	mA
Peak Current	IPK	T <sub>J</sub> = +25°C		-	2.2	-	Α

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Changes in VO due to heating effects must be taken into account separately. Pulse testing with low duty is used.

### Electrical Characteristics (MC7908) (Continued)

(VI = -14V, IO = 500mA,  $0^{\circ}$ C  $\leq$ TJ  $\leq$  +125 $^{\circ}$ C, CI =2.2 $\mu$ F, CO =1 $\mu$ F, unless otherwise specified.)

Parameter	Symbol	Cor	nditions	Min.	Тур.	Max.	Unit
		T <sub>J</sub> = +25°C		-7.7	-8	-8.3	
Output Voltage	Vo	IO = 5mA to 1A V <sub>I</sub> = -10V to -2	-	-7.6	-8	-8.4	V
Line Regulation (Note1)	ΔVΩ	T <sub>J</sub> = +25°C	V <sub>I</sub> = -10.5V to -25V	-	10	160	mV
Line Regulation (Note1)	ΔνΟ	1J = +25 C	V <sub>I</sub> = -11V to -17V	-	5	80	IIIV
Load Regulation (Note1)	ΔVΩ	$T_J = +25^{\circ}C$ $I_O = 5mA \text{ to } 1.5$	T <sub>J</sub> = +25°C I <sub>O</sub> = 5mA to 1.5A T <sub>J</sub> =+25°C I <sub>O</sub> = 250mA to 750mA		12	160	mV
Load Negulation (Note I)	ΔνΟ				4	80	IIIV
Quiescent Current	IQ	TJ =+25°C		-	3	6	mA
Quiescent Current Change	Alo	$\Delta I_Q$ $I_O = 5mA \text{ to } 1A$		-	0.05	0.5	mA
Quiescent Current Change	ΔIQ	V <sub>I</sub> = -10.5V to	-25V	-	0.1	1	ША
Temperature Coefficient of VD	ΔVo/ΔΤ	IO = 5mA		-	-0.6	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100 T <sub>A</sub> =+25°C	OkHz	-	175	-	μV
Ripple Rejection	RR	f = 120Hz ΔV <sub>I</sub> = 10V		54	60	1	dB
Dropout Voltage	VD	T <sub>J</sub> = +25°C I <sub>O</sub> = 1A		-	2	-	٧
Short Circuit Current	Isc	TJ = +25°C, VI	= -35V	-	300	-	mA
Peak Current	IPK	T <sub>J</sub> = +25°C		i	2.2	-	Α

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Changes in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

## Electrical Characteristics (MC7909) (Continued)

(VI = -15V, IO = 500mA,  $0^{\circ}$ C  $\leq$ TJ  $\leq$  +125 $^{\circ}$ C, CI =2.2 $\mu$ F, CO =1 $\mu$ F, unless otherwise specified.)

Parameter	Symbol	Con	ditions	Min.	Тур.	Max.	Unit
		T <sub>J</sub> = +25°C	T <sub>J</sub> = +25°C		-9.0	-9.3	
Output Voltage	Vo	IO = 5mA to 1A, V <sub>I</sub> = -1.5V to -23		-8.6	-9.0	-9.4	V
Line Regulation (Note1)	ΔVΩ	T <sub>J</sub> = +25°C	VI = -11.5V to -26V	-	10	180	mV
Line Regulation (Note I)	ΔνΟ	1J = +25 C	V <sub>I</sub> = -12V to -18V	-	5	90	IIIV
Load Regulation (Note1)	ΔVο	$I_{\Omega} = 5 \text{mA to } 1.5 \text{A}$		-	12	180	mV
Load (Note I)	ΔνΟ	T <sub>J</sub> = +25°C I <sub>O</sub> = 250mA to 7			4	90	''''
Quiescent Current	IQ	TJ = +25°C		-	3	6	mA
Quiescent Current Change	ΔlQ	IO = 5mA to 1A		-	0.05	0.5	mA
Quiescent Current Change	ΔiQ	V <sub>I</sub> = -11.5V to -2	e6V	-	0.1	1	IIIA
Temperature Coefficient of VD	ΔVο/ΔΤ	IO = 5mA		-	-0.6	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100k T <sub>A</sub> = +25°C	:Hz	-	175	-	μV
Ripple Rejection	RR	f = 120Hz ΔV <sub>I</sub> = 10V		54	60	-	dB
Dropout Voltage	VD	T <sub>J</sub> = +25°C I <sub>O</sub> = 1A		-	2	-	V
Short Circuit Current	Isc	TJ = +25°C, VI =	TJ = +25°C, VI = -35V		300	-	mA
Peak Current	IPK	T <sub>J</sub> = +25°C		-	2.2	-	А

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Changes in VO due to heating effects must be taken into account separately. Pulse testing with low duty is used.

## Electrical Characteristics (MC7910) (Continued)

(VI = -17V, IO = 500mA,  $0^{\circ}$ C  $\leq$ TJ  $\leq$  +125 $^{\circ}$ C, CI =2.2 $\mu$ F, CO =1 $\mu$ F, unless otherwise specified.)

Parameter	Symbol	Con	ditions	Min.	Тур.	Max.	Unit
		T <sub>J</sub> = +25°C		-9.6	-10	-10.4	
Output Voltage	Vo	IO = 5mA to 1A, VI = -12V to -28	Pd ≤ 15W	-9.5	-10	-10.5	V
Line Regulation (Note1)	ΔVο	T <sub>J</sub> = +25°C	V <sub>I</sub> = -12.5V to -28V	-	12	200	mV
Line Regulation (Note I)	ΔνΟ	1J = +25 C	V <sub>I</sub> = -14V to -20V	-	6	100	1 1111
Load Regulation (Note1)	ΔVο	T <sub>J</sub> = +25°C I <sub>O</sub> = 5mA to 1.5A		-	12	200	mV
Load (Note I)	ΔνΟ	$T_J = +25^{\circ}C$ $I_O = 250 \text{mA to } 7$			4	100	1110
Quiescent Current	IQ	TJ = +25°C		-	3	6	mA
Quiescent Current Change	ΔlQ	IO = 5mA to 1A		-	0.05	0.5	mA
Quiescent Current Change	ΔiQ	V <sub>I</sub> = -12.5V to -2	8V	-	0.1	1	
Temperature Coefficient of VO	ΔVο/ΔΤ	IO = 5mA		-	-1	-	mV/°C
Output Noise Voltage	VN	10Hz ≤ f ≤ 100kH T <sub>A</sub> =+25°C	<del>l</del> z	-	280	-	μV
Ripple Rejection	RR	f = 120Hz ΔV <sub>I</sub> = 10V		54	60	-	dB
Dropout Voltage	VD	TJ = +25°C I <sub>O</sub> = 1A		-	2	-	V
Short Circuit Current	Isc	T <sub>J</sub> = +25°C, V <sub>I</sub> = -35V		-	300	-	mA
Peak Current	IPK	T <sub>J</sub> = +25°C		-	2.2	-	Α

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Changes in VO due to heating effects must be taken into account separately. Pulse testing with low duty is used.

## Electrical Characteristics (MC7912) (Continued)

(VI = -19V, IO = 500mA,  $0^{\circ}$ C  $\leq$ TJ  $\leq$  +125 $^{\circ}$ C, CI =2.2 $\mu$ F, CO =1 $\mu$ F, unless otherwise specified.)

Parameter	Symbol	Cor	nditions	Min.	Тур.	Max.	Unit
		T <sub>J</sub> = +25°C		-11.5	-12	-12.5	
Output Voltage	Vo	IO = 5mA  to  1A, $V_I = -15.5V \text{ to } -2$		-11.4	-12	-12.6	s V
Line Regulation (Note1)	ΔVΩ	T <sub>J</sub> = +25°C	V <sub>I</sub> = -14.5V to -30V	-	12	240	mV
Line Regulation (Note1)	ΔνΟ	V <sub>I</sub> = -16V to -22V		-	6	120	IIIV
Load Regulation (Note1)	ΔVΩ	$T_J = +25^{\circ}C$ $I_O = 5mA \text{ to } 1.5A$	IO = 5mA to 1.5A		12	240	mV
Load Regulation (Note 1)	ΔνΟ	$T_J = +25^{\circ}C$ $I_O = 250mA \text{ to } 7$			- 4	120	IIIV
Quiescent Current	IQ	TJ = +25°C	T <sub>J</sub> = +25°C		3	6	mA
Quiescent Current Change	Alo	ΔIQ IO = 5mA to 1A		-	0.05	0.5	mA
Quiescent Current Change	ΔIQ	$V_I = -14.5V \text{ to } -3$	80V	-	0.1	1	ША
Temperature Coefficient of VD	ΔVο/ΔΤ	IO = 5mA		-	-0.8	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100k T <sub>A</sub> = +25°C	Hz	-	200	-	μV
Ripple Rejection	RR	f = 120Hz ΔV <sub>I</sub> = 10V			60	-	dB
Dropout Voltage	VD	T <sub>J</sub> = +25°C I <sub>O</sub> = 1A		-	2	-	V
Short Circuit Current	Isc	TJ = +25°C, VI =	-35V	-	300	-	mA
Peak Current	IPK	T <sub>J</sub> = +25°C		-	2.2	-	Α

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Changes in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

## Electrical Characteristics (MC7915) (Continued)

(VI = -23V, IO = 500mA,  $0^{\circ}$ C  $\leq$ TJ  $\leq$  +125 $^{\circ}$ C, CI =2.2 $\mu$ F, CO =1 $\mu$ F, unless otherwise specified.)

Parameter	Symbol	Con	ditions	Min.	Тур.	Max.	Unit
		T <sub>J</sub> = +25°C		-14.4	-15	-15.6	
Output Voltage	Vo	IO = 5mA  to  1A, $V_I = -18V \text{ to } -30$		-14.25	-15	-15.75	V
Line Regulation (Note1)	ΔVΩ	T <sub>J</sub> = +25°C	VI = -17.5V to -30V	-	12	300	mV
Line Regulation (Note 1)	ΔνΟ	1J = <del>1</del> 25 C	V <sub>I</sub> = -20V to -26V	-	6	150	IIIV
Load Regulation (Note1)	ΔVο	$T_J = +25^{\circ}C$ $I_O = 5mA \text{ to } 1.5a$	A	-	12	300	mV
Load Negulation (Note 1)	Δ۷Ο	$T_J = +25^{\circ}C$ $I_O = 250 \text{mA to } 7$			4	150	IIIV
Quiescent Current	IQ	TJ = +25°C		-	3	6	mA
Quiescent Current Change	ΔlQ	$I_O = 5mA \text{ to } 1A$		-	0.05	0.5	mA
Quiescent Current Change	ΔiQ	$V_I = -17.5V \text{ to } -3$	30V	-	0.1	1	
Temperature Coefficient of VD	ΔVο/ΔΤ	IO = 5mA		-	-0.9	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100k T <sub>A</sub> =+25°C	kHz	-	250	-	μV
Ripple Rejection	RR	f = 120Hz $\Delta V_I = 10V$		54	60	-	dB
Dropout Voltage	VD	T <sub>J</sub> = +25°C I <sub>O</sub> = 1A		-	2	-	V
Short Circuit Current	Isc	TJ = +25°C, VI =	= -35V	-	300	-	mA
Peak Current	IPK	T <sub>J</sub> = +25°C		-	2.2	-	Α

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Changes in VO due to heating effects must be taken into account separately. Pulse testing with low duty is used.

## Electrical Characteristics (MC7918) (Continued)

(VI = -27V, IO = 500mA,  $0^{\circ}$ C  $\leq$ TJ  $\leq$  +125 $^{\circ}$ C, CI =2.2 $\mu$ F, CO =1 $\mu$ F, unless otherwise specified.)

Parameter	Symbol	Con	ditions	Min.	Тур.	Max.	Unit
		T <sub>J</sub> = +25°C		-17.3	-18	-18.7	
Output Voltage	Vo	IO = 5mA to 1A, VI = -22.5V to -3		-17.1	-18	-18.9	V
Line Regulation (Note1)	ΔVΩ	T <sub>J</sub> = +25°C	V <sub>I</sub> = -21V to -33V	-	15	360	mV
Line Regulation (Note I)	ΔνΟ	11 = +23 C	V <sub>I</sub> = -24V to -30V	-	8	180	IIIV
Load Regulation (Note1)	ΔVΩ	T <sub>J</sub> = +25°C I <sub>O</sub> = 5mA to 1.5A		-	15	360	mV
Load Negulation (Note 1)	ΔνΟ	T <sub>J</sub> = +25°C l <sub>O</sub> = 250mA to 7			5	180	
Quiescent Current	IQ	TJ = +25°C		-	3	6	mA
Quiocaant Current Change	Alo	I <sub>O</sub> = 5mA to 1A		-	0.05	0.5	mA
Quiescent Current Change	ΔlQ	VI = -21V to -33V	V	-	0.1	1	IIIA
Temperature Coefficient of VD	ΔVo/ΔΤ	IO = 5mA		-	-1	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100k T <sub>A</sub> = +25°C	Hz	-	300	-	μV
Ripple Rejection	RR	f = 120Hz ΔV <sub>I</sub> = 10V		54	60	-	dB
Dropout Voltage	VD	T <sub>J</sub> = +25°C I <sub>O</sub> = 1A		-	2	-	V
Short Circuit Current	Isc	T <sub>J</sub> = +25°C, V <sub>I</sub> = -35V		-	300	-	mA
Peak Current	IPK	T <sub>J</sub> = +25°C		-	2.2	-	Α

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Changes in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

## Electrical Characteristics (MC7924) (Continued)

(VI = -33V, IO = 500mA,  $0^{\circ}$ C  $\leq$ TJ  $\leq$  +125 $^{\circ}$ C, CI =2.2 $\mu$ F, CO =1 $\mu$ F, unless otherwise specified.)

Parameter	Symbol	Cor	nditions	Min.	Тур.	Max.	Unit
		T <sub>J</sub> = +25°C		-23	-24	-25	
Output Voltage	Vo	IO = 5mA  to  1A, $V_I = -27V \text{ to } -38^{\circ}$		-22.8	-24	-25.2	V
Line Regulation (Note1)	ΔVο	T <sub>J</sub> = +25°C	V <sub>I</sub> = -27V to -38V	-	15	480	mV
Line Regulation (Note I)	ΔνΟ	1J = <del>1</del> 23 C	$V_I = -30V \text{ to } -36V$	-	8	180	
Load Regulation (Note1)	ΔVο	$T_J = +25^{\circ}C$ $I_O = 5mA \text{ to } 1.5n$	Ą	-	15	480	mV
Load (Negulation (Note 1)	ΔνΟ	$T_J = +25^{\circ}C$ $I_O = 250 \text{mA to } 7$	50mA	-	5	240	
Quiescent Current	IQ	TJ = +25°C		-	3	6	mA
Quiescent Current Change	ΔlQ	$I_O = 5mA$ to $1A$		-	0.05	0.5	mA
Quiescent Current Change	ΔiQ	VI = -27V to -38	V	=	0.1	1	1 111/4
Temperature Coefficient of VD	ΔVο/ΔΤ	IO = 5mA		-	-1	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100k T <sub>A</sub> = +25°C	кНz	-	400	-	μV
Ripple Rejection	RR	f = 120Hz ΔVI = 10V			60	-	dB
Dropout Voltage	VD	T <sub>J</sub> = +25°C I <sub>O</sub> = 1A		-	2	-	V
Short Circuit Current	Isc	TJ = +25°C, VI =	35V	-	300	-	mA
Peak Current	IPK	T <sub>J</sub> = +25°C		-	2.2	-	Α

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Changes in VO due to heating effects must be taken into account separately. Pulse testing with low duty is used.

## Electrical Characteristics (MC7905A) (Continued)

(VI = -10V, IO = 500mA,  $0^{\circ}$ C  $\leq$ TJ  $\leq$  +125 $^{\circ}$ C, CI =2.2 $\mu$ F, CO =1 $\mu$ F, unless otherwise specified.)

Parameter	Symbol	Ce	onditions	Min.	Тур.	Max.	Unit
		$T_J = +25^{\circ}C$		-4.9	-5.0	-5.1	
Output Voltage	Vo	V <sub>I</sub> = -7V to -20V		- 4.8	-5.0	-5.2	V
		T <sub>J</sub> = +25°C	V <sub>I</sub> = -7V to -20V I <sub>O</sub> =1A	-	5	50	
Line Regulation (Note1)	ΔVο	1J = +25 C	V <sub>I</sub> = -8V to -12V I <sub>O</sub> =1A	-	2	25	mV
Line Regulation (Note I)	ΔνΟ	V <sub>I</sub> = -7.5V to -25V	V	-	7	50	IIIV
		V <sub>I</sub> = -8V to -12V , I <sub>O</sub> =1A		-	7	50	
		TJ =+25°C, IO =	5mA to 1.5A	-	10	100	
Load Regulation (Note1)		$T_J = +25^{\circ}C$ IO = 250mA to 750mA		-	3	50	mV
Quiescent Current	ΙQ	T <sub>J</sub> = +25°C			3	6	mA
Quiagont Current Change	Alo	IO = 5mA to 1A		-	0.05	0.5	mA
Quiescent Current Change	ΔlQ	V <sub>I</sub> = -8V to -25V		-	0.1	0.8	MA
Temperature Coefficient of VD	ΔVο/ΔΤ	IO = 5mA		-	- 0.4	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100kl T <sub>A</sub> = +25°C	Hz	-	40	-	μV
Ripple Rejection	RR	f = 120Hz ΔV <sub>I</sub> = 10V		54	60	-	dB
Dropout Voltage	VD	T <sub>J</sub> = +25°C I <sub>O</sub> = 1A		-	2	-	V
Short Circuit Current	Isc	TJ = +25°C, VI =	-35V	-	300	-	mA
Peak Current	IPK	T <sub>J</sub> = +25°C		-	2.2	-	Α

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Changes in VO due to heating effects must be taken into account separately. Pulse testing with low duty is used.

## Electrical Characteristics (MC7912A) (Continued)

(VI = -19V, IO = 500mA,  $0^{\circ}$ C  $\leq$ TJ  $\leq$  +125 $^{\circ}$ C, CI =2.2 $\mu$ F, CO =1 $\mu$ F, unless otherwise specified.)

Parameter	Symbol	Cor	nditions	Min.	Тур.	Max.	Unit
		T <sub>J</sub> = +25°C		-11.75	-12	-12.25	
Output Voltage	Vo	IO = 5mA to 1A, V <sub>I</sub> = -15.5V to -2		-11.5	-12	-12.5	V
		T <sub>J</sub> = +25°C	V <sub>I</sub> = -14.5V to -27V lo = 1A	-	12	120	
Line Regulation (Note1)	ΔVο	1J = +23 C	V <sub>I</sub> = -16V to -22V lo = 1A	-	6	60	mV
		$V_{I} = -14.8V \text{ to } -3$	0V	-	12	120	
		V <sub>I</sub> = -16V to -22V, lo = 1A		-	12	120	
Load Demulation (Noted)	ΔVο	T <sub>J</sub> = +25°C l <sub>O</sub> = 5mA to 1.5/	Γ <sub>J</sub> = +25°C <sub>O</sub> = 5mA to 1.5A		12	150	mV
Load Regulation (Note1)		TJ = +25°C IO = 250mA to 750mA		-	4	75	IIIV
Quiescent Current	IQ	TJ = +25°C		-	3	6	mA
Ouissant Current Change		$I_O = 5mA \text{ to } 1A$		-	0.05	0.5	A
Quiescent Current Change	ΔlQ	VI = -15V to -30	V	-	0.1	1	mA
Temperature Coefficient of VD	ΔVο/ΔΤ	IO = 5mA		-	-0.8	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100k T <sub>A</sub> = +25°C	Hz	-	200	-	μV
Ripple Rejection	RR	f = 120Hz ΔV <sub>I</sub> = 10V			60	-	dB
Dropout Voltage	VD	T <sub>J</sub> = +25°C I <sub>O</sub> = 1A		-	2	-	V
Short Circuit Current	Isc	T <sub>J</sub> = +25°C, V <sub>I</sub> =	: -35V	-	300	-	mA
Peak Current	IPK	T <sub>J</sub> = +25°C		-	2.2	-	Α

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Changes in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

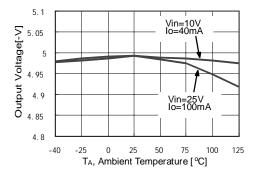
## Electrical Characteristics (MC7915A) (Continued)

(VI = -23V, IO = 500mA,  $0^{\circ}$ C  $\leq$ TJ  $\leq$  +125 $^{\circ}$ C, CI =2.2 $\mu$ F, CO =1 $\mu$ F, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
	Vo	T <sub>J</sub> = +25°C		-14.7	-15	-15.3	V
Output Voltage		IO = 5mA to 1A, PO ≤ 15W VI = -18V to -30V		-14.4	-15	-15.6	
Line Regulation (Note1)	ΔVο	TJ = +25°C	V <sub>I</sub> = -17.5V to -30V Io = 1A	-	12	150	mV
			VI = -20V to -26V Io = 1A	-	6	75	
		V <sub>I</sub> = -17.9V to -30V		-	12	150	
		V <sub>I</sub> = -20V to -26V, Io = 1A		-	6	150	
Load Regulation (Note1)	ΔVο	$T_{J} = +25^{\circ}C$ $I_{O} = 5mA \text{ to } 1.5A$		-	12	150	mV
		T <sub>J</sub> = +25°C I <sub>O</sub> = 250mA to 750mA		-	4	75	
Quiescent Current	lQ	T <sub>J</sub> = +25°C		-	3	6	mA
Quiescent Current Change	ΔlQ	I <sub>O</sub> = 5mA to 1A		-	0.05	0.5	mA
		V <sub>I</sub> = -18.5V to -30V		-	0.1	1	
Temperature Coefficient of VD	ΔVo/ΔΤ	IO = 5mA		-	-0.9	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100kHz T <sub>A</sub> = +25°C		-	250	-	μV
Ripple Rejection	RR	f = 120Hz $\Delta V_I = 10V$		54	60	-	dB
Dropout Voltage	VD	T <sub>J</sub> = +25°C I <sub>O</sub> = 1A		-	2	-	V
Short Circuit Current	Isc	T <sub>J</sub> = +25°C, V <sub>I</sub> = -35V		-	300	-	mA
Peak Current	IPK	T <sub>J</sub> = +25°C		-	2.2	-	Α

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Changes in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

### **Typical Perfomance Characteristics**



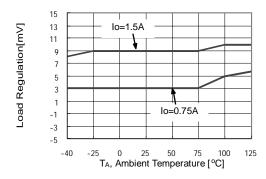
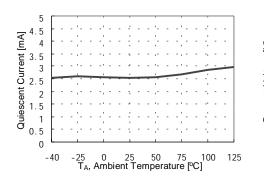


Figure 1. Output Voltage

Figure 2. Load Regulation



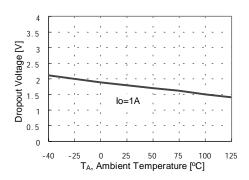


Figure 3. Quiescent Current

Figure 4. Dropout Voltage

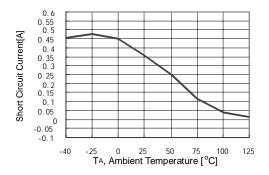


Figure 5. Short Circuit Current

### **Typical Applications**

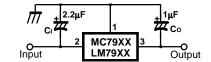


Figure 6. Negative Fixed output regulator

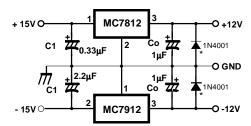


Figure 7. Split power supply (  $\pm$  12V/1A)

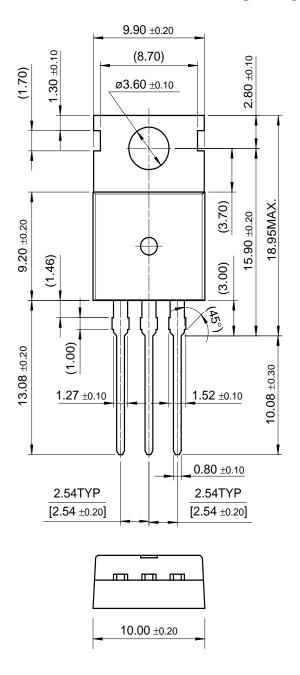
- (1) To specify an output voltage, substitute voltage value for "XX"
- (2) Required for stability. For value given, capacitor must be solid tantalum. If aluminium electronics are used, at least ten times value shown should be selected. C<sub>I</sub> is required if regulator is located an appreciable distance from power supply filter.
- (3) To improve transient response. If large capacitors are used, a high current diode from input to output (1N400l or similar) should be introduced to protect the device from momentary input short circuit.

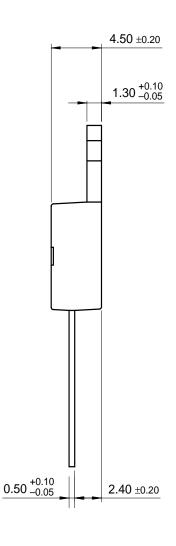
### **Mechanical Dimensions**

### Package

### **Dimensions in millimeters**

**TO-220** 





# **Ordering Information**

Product Number	Output Voltage Tolerance	Package	Operating Temperature	
LM7905CT	±4%	TO-220	0 ~ +125°C	
Product Number	Output Voltage Tolerance	Package	Operating Temperature	
MC7905CT				
MC7906CT				
MC7908CT				
MC7909CT				
MC7910CT	±4%			
MC7912CT		TO-220	0 ~ +125°C	
MC7915CT		10-220	0~+125 0	
MC7918CT				
MC7924CT				
MC7905ACT				
MC7912ACT	±2%			
MC7915ACT				

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